



10-FY07NBA225S502-M507L98

datasheet

Vincotech

| flowBOOST 1 symmetric | | 650 V / 225 A |
|--|--|-----------------------------|
| Features | | |
| • High efficient and compact symmetric booster • High switching frequency and low inductive design • Low losses with TRENCHSTOP™ 5 IGBT • Integrated temperature sensor | | |
| Target applications | | flow 1 12 mm housing |
| • Power Supply • Solar Inverters | | |
| Types | | Schematic |
| • 10-FY07NBA225S502-M507L98 | | |

Maximum Ratings

 $T_j = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Condition | Value | Unit |
|-----------------------------------|------------|---|----------|------------------|
| Boost Switch | | | | |
| Collector-emitter voltage | V_{CES} | | 650 | V |
| Collector current | I_C | $T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ | 147 | A |
| Repetitive peak collector current | I_{CRM} | t_p limited by T_{jmax} | 675 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$ | 197 | W |
| Gate-emitter voltage | V_{GES} | | ± 20 | V |
| Maximum junction temperature | T_{jmax} | | 175 | $^\circ\text{C}$ |



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Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Condition | Value | Unit |
|-------------------------------------|------------|------------------|-------|------------------|
| Boost Diode | | | | |
| Peak repetitive reverse voltage | V_{RRM} | | 650 | V |
| Continuous (direct) forward current | I_F | $T_j = T_{jmax}$ | 145 | A |
| Repetitive peak forward current | I_{FRM} | | 450 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ | 178 | W |
| Maximum junction temperature | T_{jmax} | | 175 | $^\circ\text{C}$ |

Boost Sw. Protection Diode

| | | | | |
|-------------------------------------|------------|------------------|-----|------------------|
| Peak Repetitive Reverse Voltage | V_{RRM} | | 650 | V |
| Continuous (direct) forward current | I_F | | 30 | A |
| Repetitive peak forward current | I_{FRM} | | 60 | A |
| Total power dissipation | P_{tot} | $T_j = T_{jmax}$ | 53 | W |
| Maximum Junction Temperature | T_{jmax} | | 175 | $^\circ\text{C}$ |

Module Properties

Thermal Properties

| | | | | |
|---|-----------|--|---------------------------|------------------|
| Storage temperature | T_{stg} | | -40...+125 | $^\circ\text{C}$ |
| Operation temperature under switching condition | T_{jop} | | -40...($T_{jmax} - 25$) | $^\circ\text{C}$ |

Isolation Properties

| | | | | | |
|----------------------------|------------|------------------|----------------------|-----------|----|
| Isolation voltage | V_{isol} | DC Test Voltage* | $t_p = 2\text{ s}$ | 6000 | V |
| | | AC Voltage | $t_p = 1\text{ min}$ | 2500 | V |
| Creepage distance | | | | min. 12,7 | mm |
| Clearance | | | | 8,44 | mm |
| Comparative Tracking Index | CTI | | | > 200 | |

*100 % tested in production



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Characteristic Values

| Parameter | Symbol | Conditions | | | | | | Value | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|-----|-------|-----|--|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_c [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | | |

Boost Switch

Static

| | | | | | | | | | | |
|--------------------------------------|--------------|---------------------|----|-----|---------|------------|-------|----------------------|------|----|
| Gate-emitter threshold voltage | $V_{GE(th)}$ | $V_{GE} = V_{CE}$ | | | 0,00225 | 25 | 3,2 | 4 | 4,8 | V |
| Collector-emitter saturation voltage | V_{CESat} | | 15 | | 225 | 125 150 | | 1,43 1,52 1,55 | 1,75 | V |
| Collector-emitter cut-off current | I_{CES} | | 0 | 650 | | 25 | | | 150 | µA |
| Gate-emitter leakage current | I_{GES} | | 20 | 0 | | 25 | | | 300 | nA |
| Internal gate resistance | r_g | | | | | | | none | | Ω |
| Input capacitance | C_{ies} | $f = 1 \text{ Mhz}$ | 0 | 25 | 25 | 25 | 13500 | | | pF |
| Output capacitance | C_{oes} | | | | | | | | | |
| Reverse transfer capacitance | C_{res} | | | | | | | | | |
| Gate charge | Q_g | | 15 | 520 | 225 | 25 | | 492 | | nC |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX) | | | | | | 0,48 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|-----------------------------|--------------|--|------|-----|-----|-----|--|-------|--|-----|
| Turn-on delay time | $t_{d(on)}$ | $R_{goff} = 2 \Omega$ $R_{gon} = 2 \Omega$ | 15/0 | 350 | 226 | 25 | | 43 | | ns |
| Rise time | t_r | | | | | 125 | | 42 | | |
| Turn-off delay time | $t_{d(off)}$ | | | | | 150 | | 43 | | |
| Fall time | t_f | $Q_{rFWD} = 5 \mu\text{C}$ $Q_{rFWD} = 10,9 \mu\text{C}$ $Q_{rFWD} = 12,9 \mu\text{C}$ | 25 | 178 | 198 | 25 | | 40 | | mWs |
| Turn-on energy (per pulse) | E_{on} | | | | | 125 | | 39 | | |
| Turn-off energy (per pulse) | E_{off} | | | | | 150 | | 40 | | |
| | | | | | | 25 | | 178 | | |
| | | | | | | 125 | | 198 | | |
| | | | | | | 150 | | 203 | | |
| | | | | | | 25 | | 29 | | |
| | | | | | | 125 | | 33 | | |
| | | | | | | 150 | | 40 | | |
| | | | | | | 25 | | 3,357 | | |
| | | | | | | 125 | | 3,931 | | |
| | | | | | | 150 | | 3,864 | | |
| | | | | | | 25 | | 3,402 | | |
| | | | | | | 125 | | 4,373 | | |
| | | | | | | 150 | | 4,868 | | |



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Characteristic Values

| Parameter | Symbol | Conditions | | | | | | Value | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|-----|-------|-----|--|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_c [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | | |

Boost Diode

Static

| | | | | | | | | | | |
|-------------------------|-------|--|--|-----|-----|-----------|--|--------------|------|----|
| Forward voltage | V_F | | | | 225 | 25 125 | | 1,53 1,49 | 1,92 | V |
| Reverse leakage current | I_R | | | 650 | | 25 | | | 11,4 | µA |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX) | | | | | | 0,53 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|

Dynamic

| | | | | | | | | | | |
|---------------------------------------|----------------------|--|------|-----|-----|-----|--|--------|--|------|
| Peak recovery current | I_{RRM} | $di/dt = 4532 \text{ A/}\mu\text{s}$ $di/dt = 5576 \text{ A/}\mu\text{s}$ $di/dt = 5500 \text{ A/}\mu\text{s}$ | 15/0 | 350 | 226 | 25 | | 110 | | A |
| Reverse recovery time | t_{rr} | | | | | 125 | | 178 | | |
| Recovered charge | Q_r | | | | | 150 | | 194 | | |
| Recovered charge | Q_r | $di/dt = 4532 \text{ A/}\mu\text{s}$ $di/dt = 5576 \text{ A/}\mu\text{s}$ $di/dt = 5500 \text{ A/}\mu\text{s}$ | 15/0 | 350 | 226 | 25 | | 65 | | ns |
| Recovered charge | Q_r | | | | | 125 | | 91 | | |
| Recovered charge | Q_r | | | | | 150 | | 103 | | |
| Reverse recovered energy | E_{rec} | $di/dt = 4532 \text{ A/}\mu\text{s}$ $di/dt = 5576 \text{ A/}\mu\text{s}$ $di/dt = 5500 \text{ A/}\mu\text{s}$ | 15/0 | 350 | 226 | 25 | | 5,047 | | µC |
| Reverse recovered energy | E_{rec} | | | | | 125 | | 10,868 | | |
| Reverse recovered energy | E_{rec} | | | | | 150 | | 12,852 | | |
| Peak rate of fall of recovery current | $(di_{rf}/dt)_{max}$ | $di/dt = 4532 \text{ A/}\mu\text{s}$ $di/dt = 5576 \text{ A/}\mu\text{s}$ $di/dt = 5500 \text{ A/}\mu\text{s}$ | 15/0 | 350 | 226 | 25 | | 1,109 | | mWs |
| Peak rate of fall of recovery current | $(di_{rf}/dt)_{max}$ | | | | | 125 | | 2,571 | | |
| Peak rate of fall of recovery current | $(di_{rf}/dt)_{max}$ | | | | | 150 | | 3,270 | | |
| Peak rate of fall of recovery current | $(di_{rf}/dt)_{max}$ | $di/dt = 4532 \text{ A/}\mu\text{s}$ $di/dt = 5576 \text{ A/}\mu\text{s}$ $di/dt = 5500 \text{ A/}\mu\text{s}$ | 15/0 | 350 | 226 | 25 | | 4953 | | A/µs |
| Peak rate of fall of recovery current | $(di_{rf}/dt)_{max}$ | | | | | 125 | | 4124 | | |
| Peak rate of fall of recovery current | $(di_{rf}/dt)_{max}$ | | | | | 150 | | 3409 | | |

Boost Sw. Protection Diode

Static

| | | | | | | | | | | |
|-------------------------|-------|--|--|-----|----|-----------|--|--------------|------|----|
| Forward voltage | V_F | | | | 30 | 25 150 | | 1,64 1,56 | 1,87 | V |
| Reverse leakage current | I_r | | | 650 | | 25 | | | 0,36 | µA |

Thermal

| | | | | | | | | | | |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|
| Thermal resistance junction to sink | $R_{th(j-s)}$ | $\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX) | | | | | | 1,80 | | K/W |
|-------------------------------------|---------------|---|--|--|--|--|--|------|--|-----|



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Characteristic Values

| Parameter | Symbol | Conditions | | | | | Value | | | Unit |
|-----------|--------|------------|------------------------------|---|-------------------------------------|------------|-------|-----|-----|------|
| | | | V_{GE} [V] V_{GS} [V] | V_{CE} [V] V_{DS} [V] V_F [V] | I_c [A] I_D [A] I_F [A] | T_j [°C] | Min | Typ | Max | |

Thermistor

| | | | | | | | | | | |
|----------------------------|----------------|-------------------------|--|--|--|-----|----|------|---|------|
| Rated resistance | R | | | | | 25 | | 22 | | kΩ |
| Deviation of R_{100} | $\Delta R/R$ | $R_{100} = 1484 \Omega$ | | | | 100 | -5 | | 5 | % |
| Power dissipation | P | | | | | 25 | | 5 | | mW |
| Power dissipation constant | | | | | | 25 | | 1,5 | | mW/K |
| B-value | $B_{(25/50)}$ | Tol. ±1 % | | | | 25 | | 3962 | | K |
| B-value | $B_{(25/100)}$ | Tol. ±1 % | | | | 25 | | 4000 | | K |
| Vincotech NTC Reference | | | | | | | | | I | |

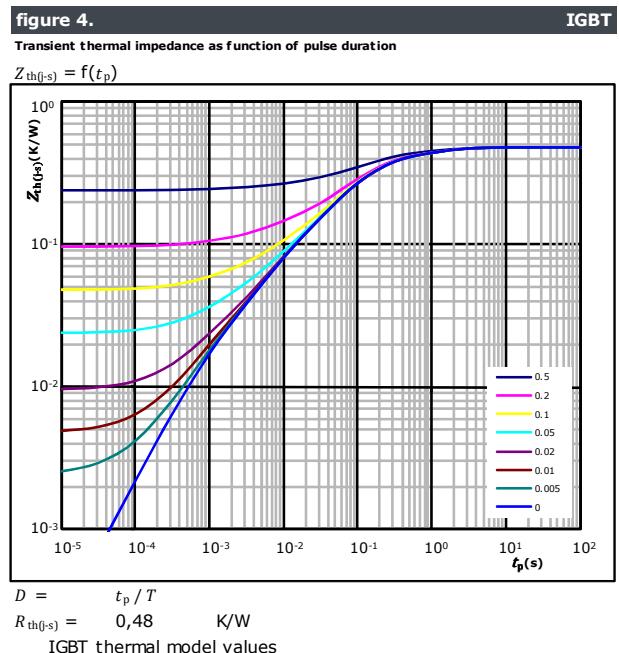
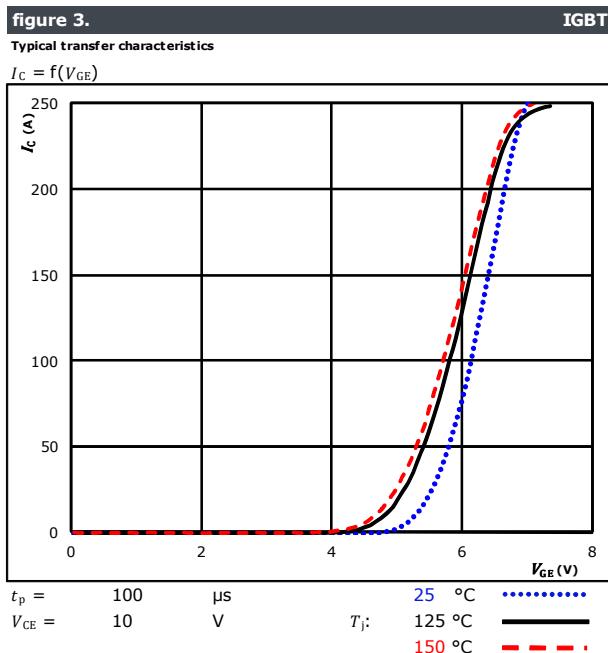
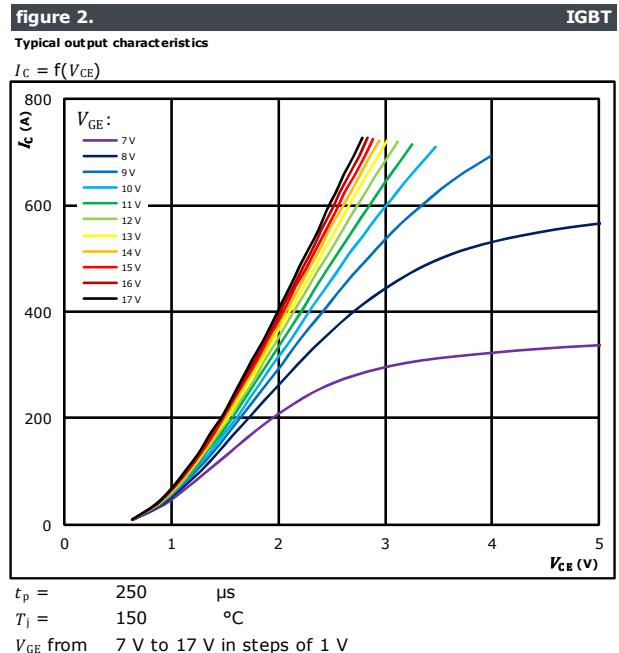
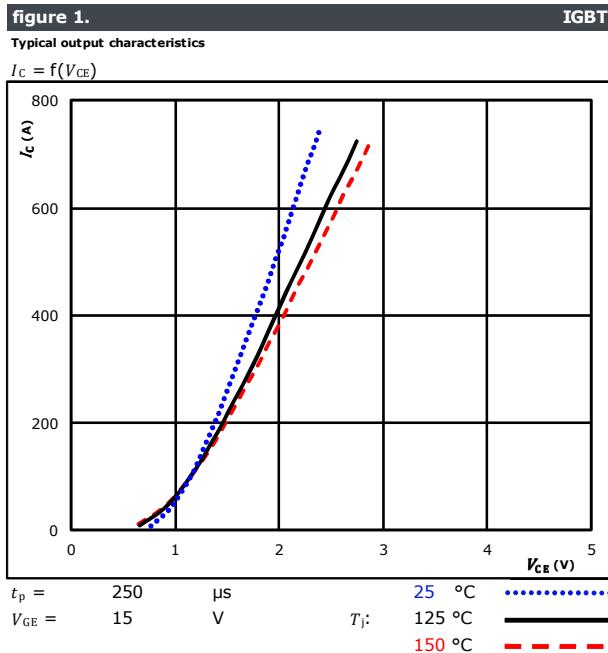


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Boost Switch Characteristics



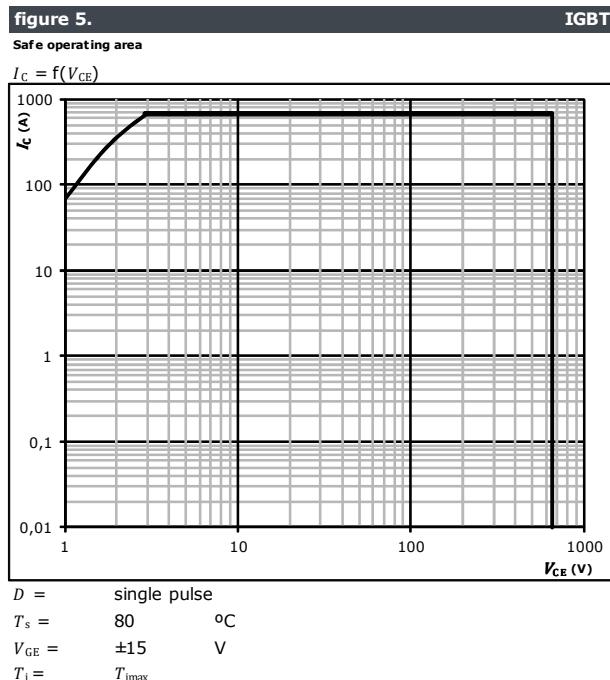


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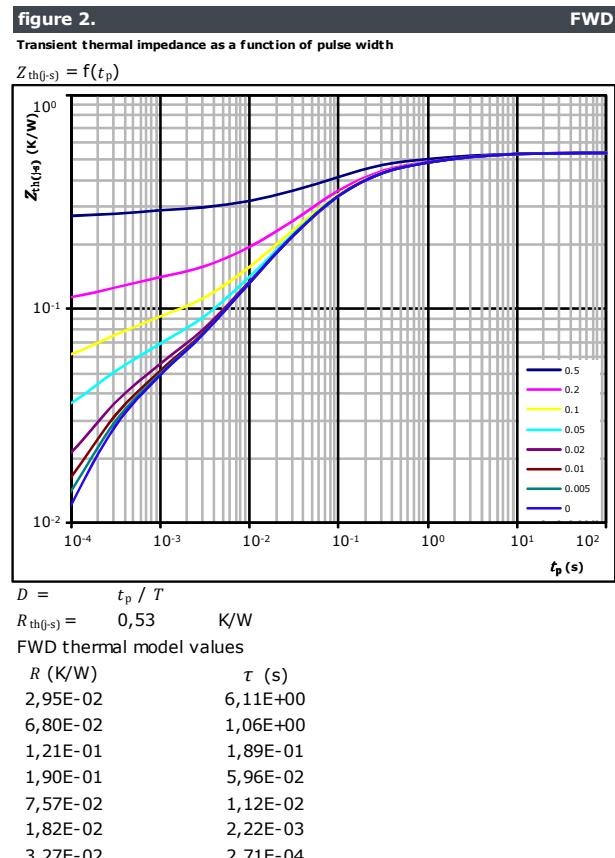
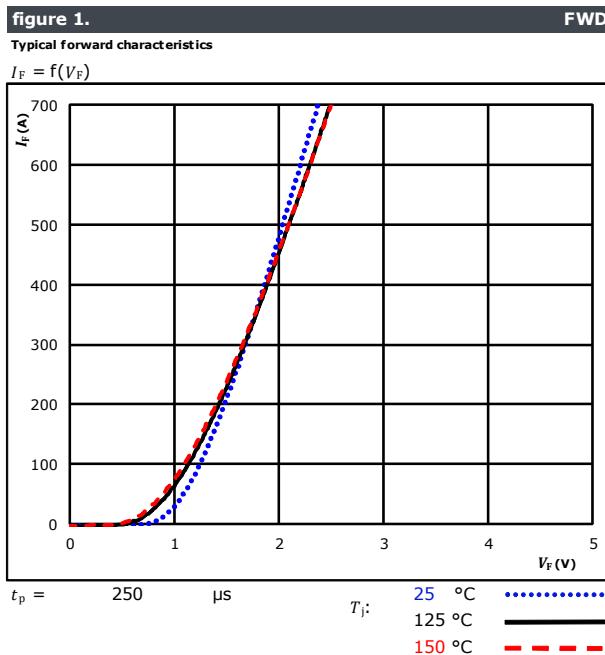
Boost Switch Characteristics





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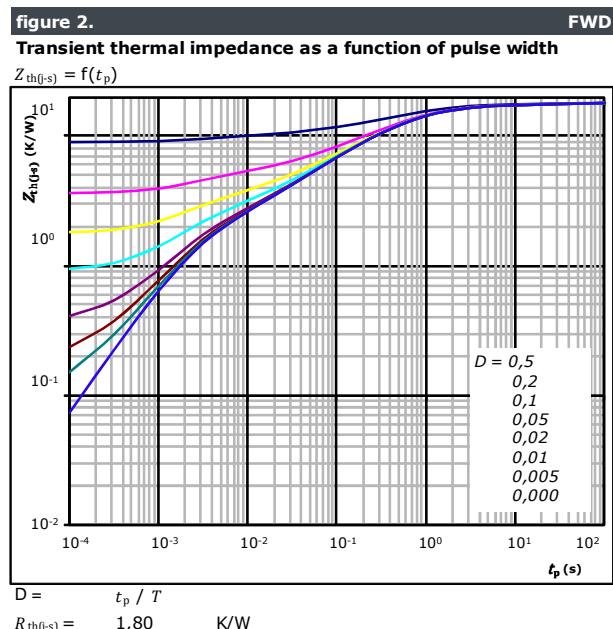
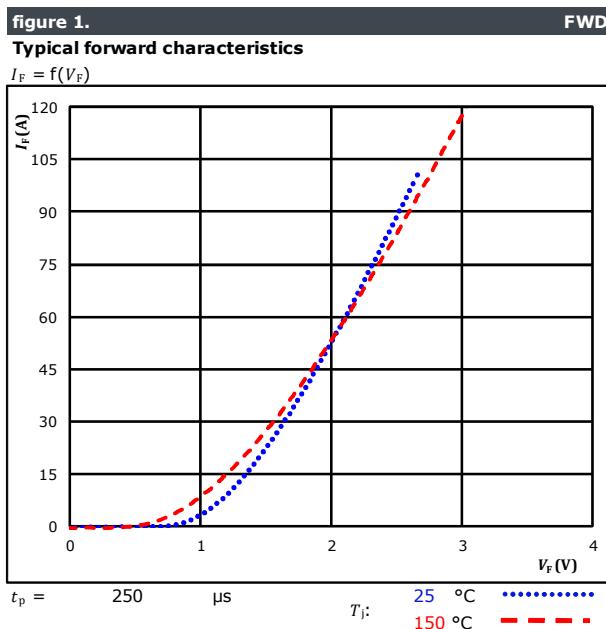
Boost Diode Characteristics





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Boost Sw. Protection Diode Characteristics



FWD thermal model values

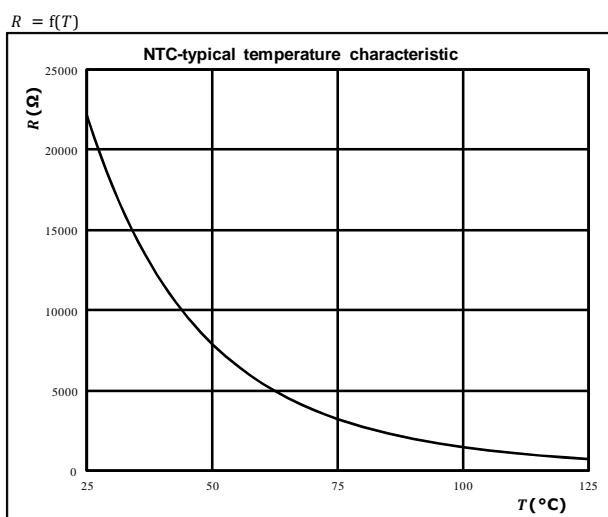
| R (K/W) | τ (s) |
|-----------|------------|
| 5,88E-02 | 5,09E+00 |
| 1,26E-01 | 6,40E-01 |
| 5,91E-01 | 8,94E-02 |
| 5,13E-01 | 2,64E-02 |
| 2,57E-01 | 6,46E-03 |
| 1,01E-01 | 1,53E-03 |



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Thermistor Characteristics

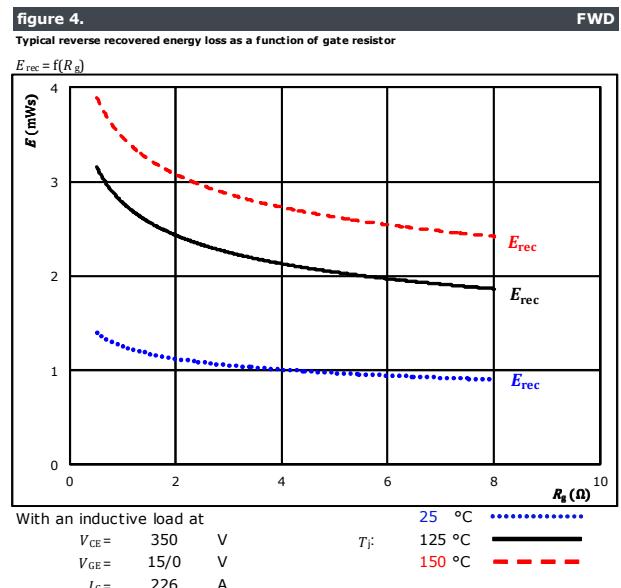
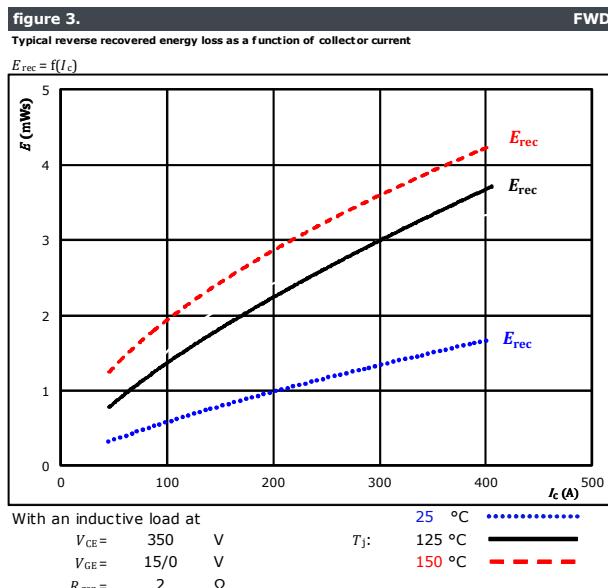
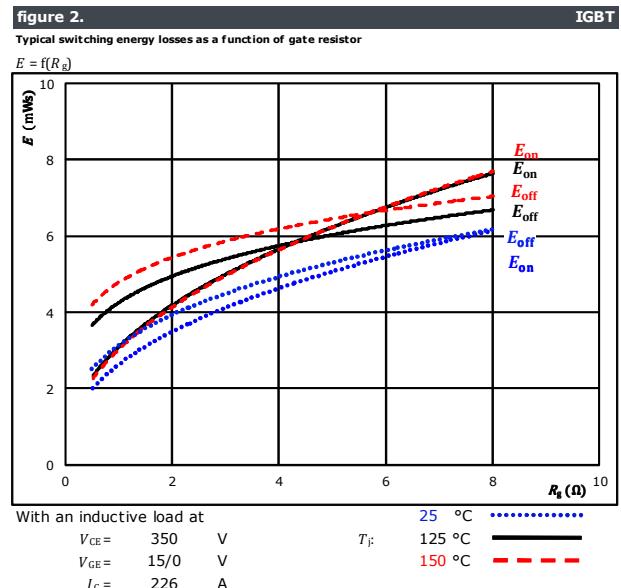
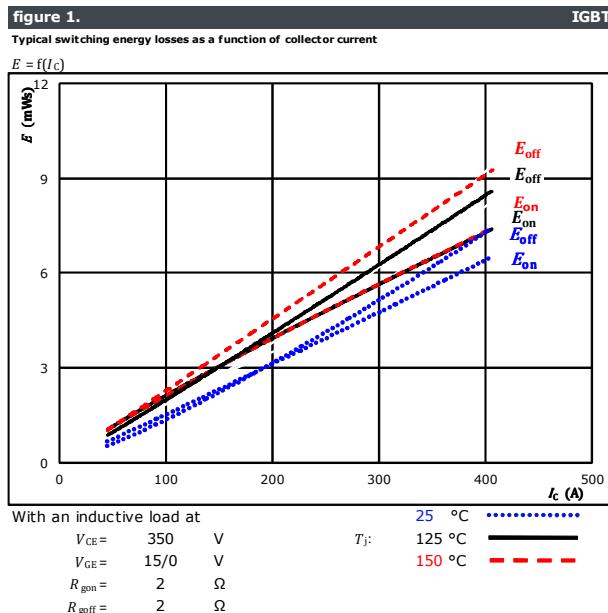
figure 1. Thermistor
Typical NTC characteristic as a function of temperature





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Boost Switching Characteristics



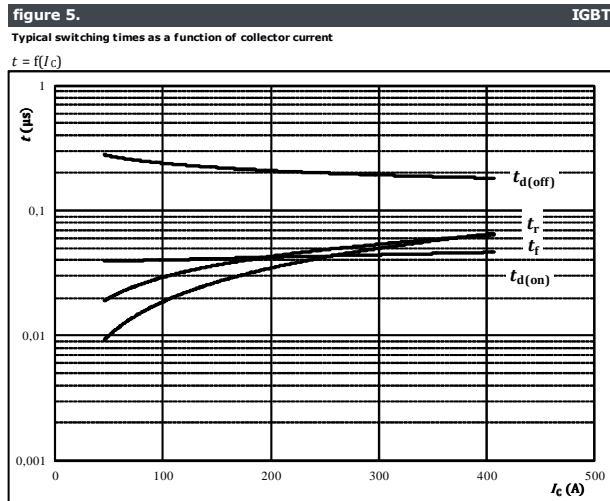


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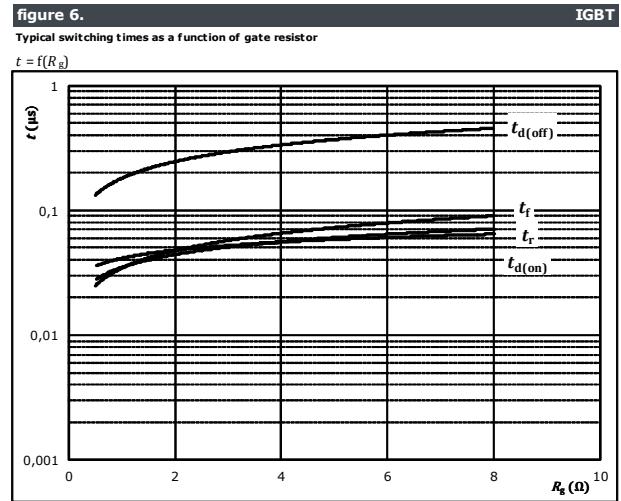
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Boost Switching Characteristics



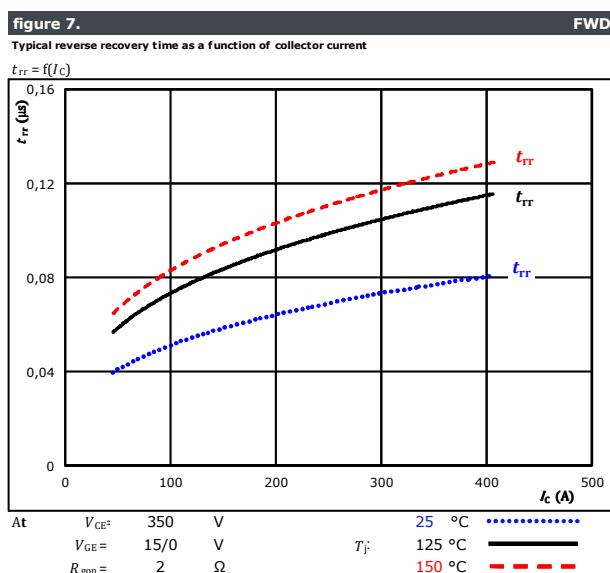
With an inductive load at

T_j = 150 °C
 V_{CE} = 350 V
 V_{GE} = 15/0 V
 R_{gon} = 2 Ω
 R_{goff} = 2 Ω



With an inductive load at

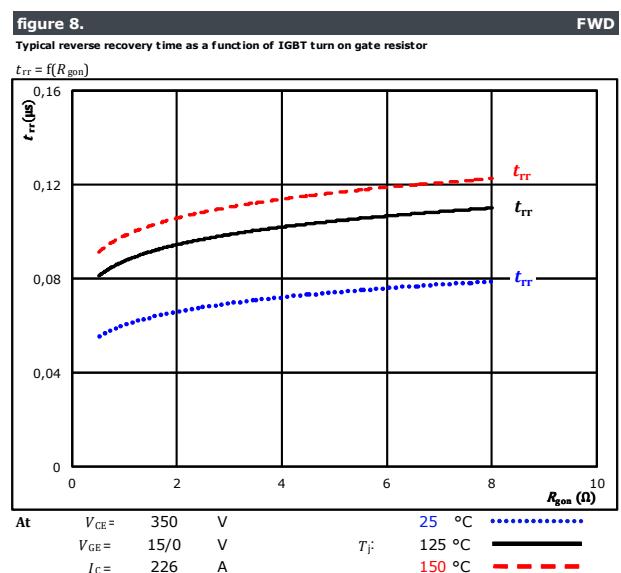
T_j = 150 °C
 V_{CE} = 350 V
 V_{GE} = 15/0 V
 I_C = 226 A



At $V_{CE} = 350$ V $T_j = 25$ °C $T_j = 125$ °C $T_j = 150$ °C

$V_{GE} = 15/0$ V $I_C = 226$ A

$R_{gon} = 2$ Ω



At $V_{CE} = 350$ V $T_j = 25$ °C $T_j = 125$ °C $T_j = 150$ °C

$V_{GE} = 15/0$ V $I_C = 226$ A

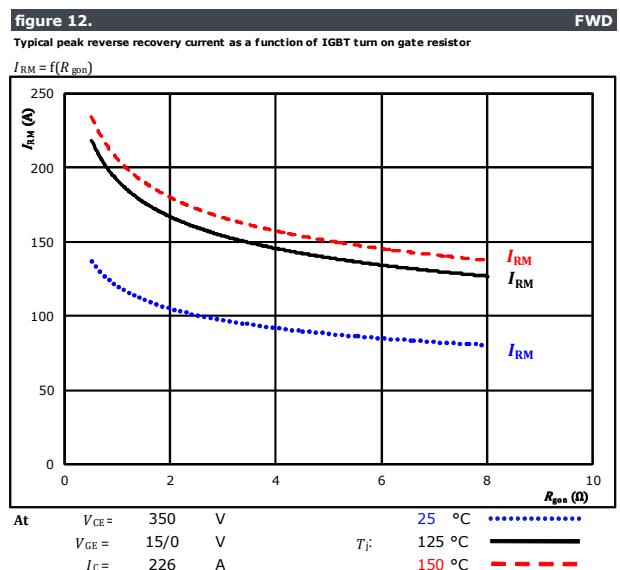
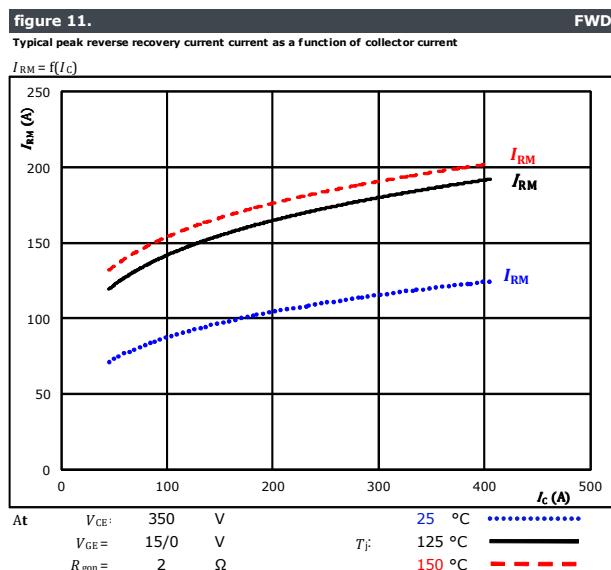
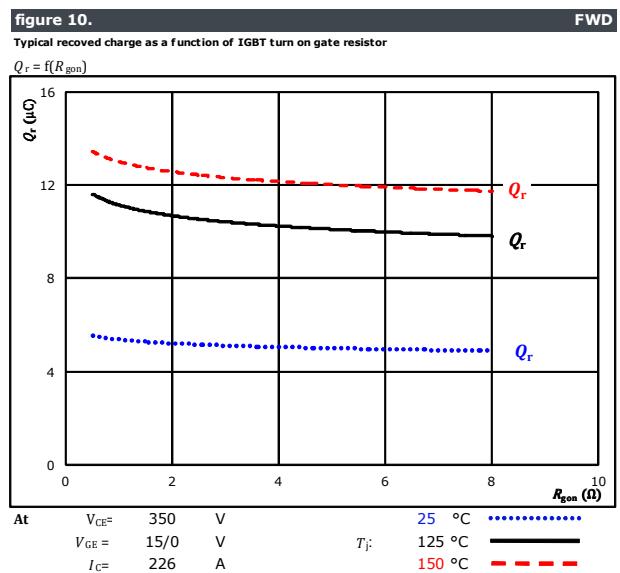
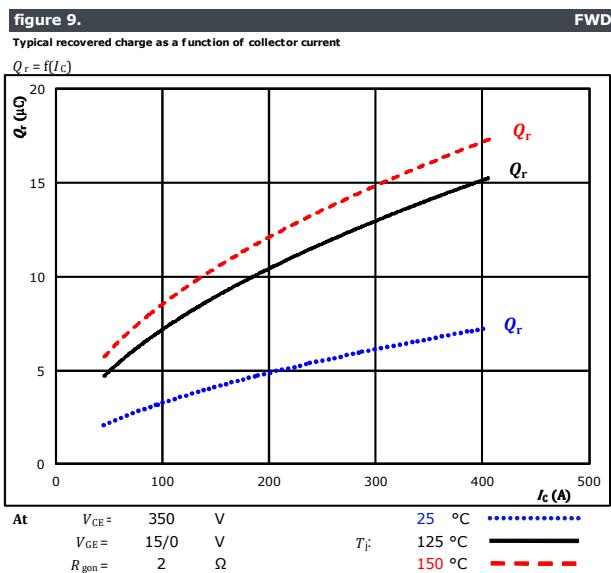


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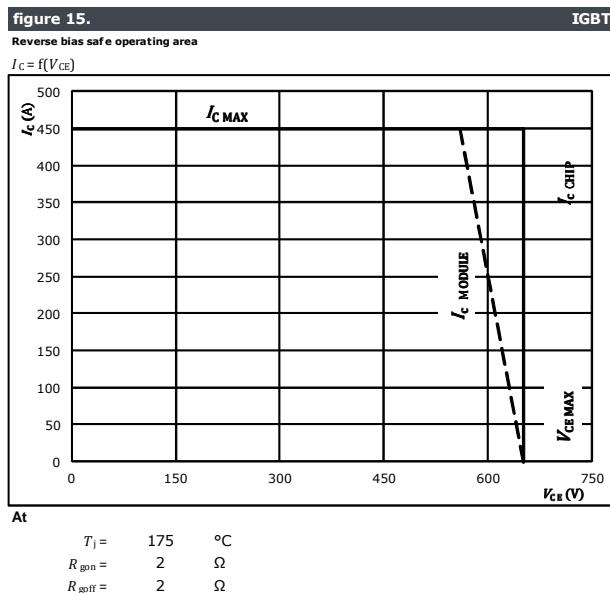
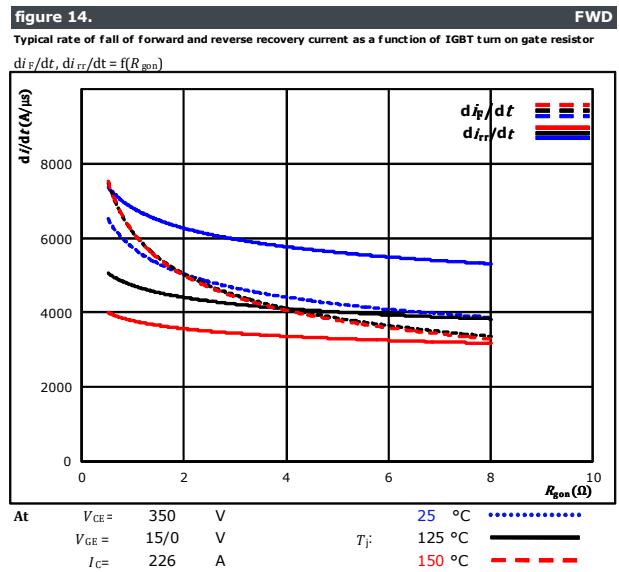
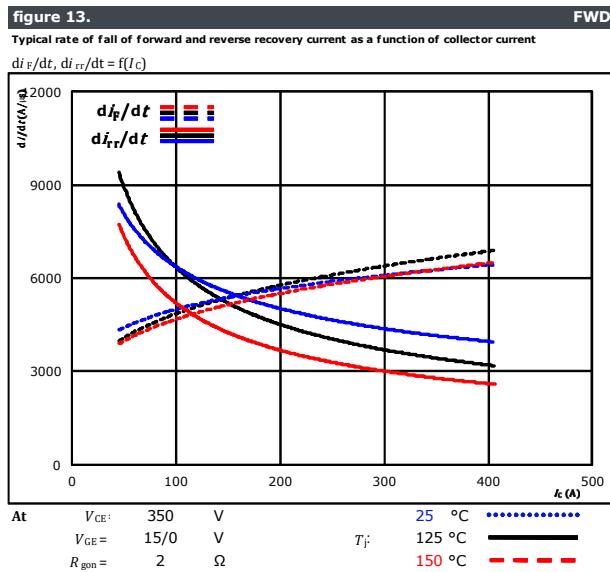
Boost Switching Characteristics





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Boost Switching Characteristics



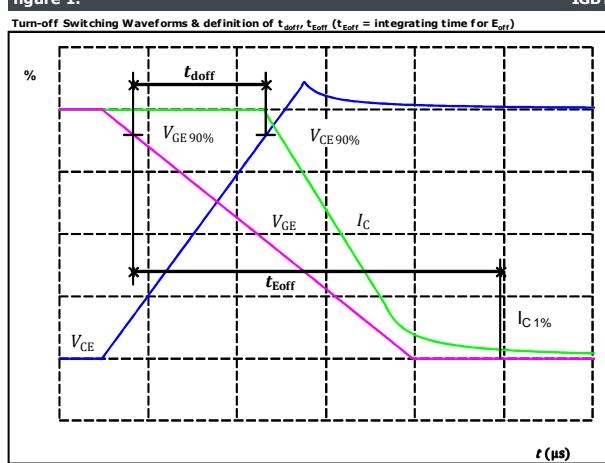
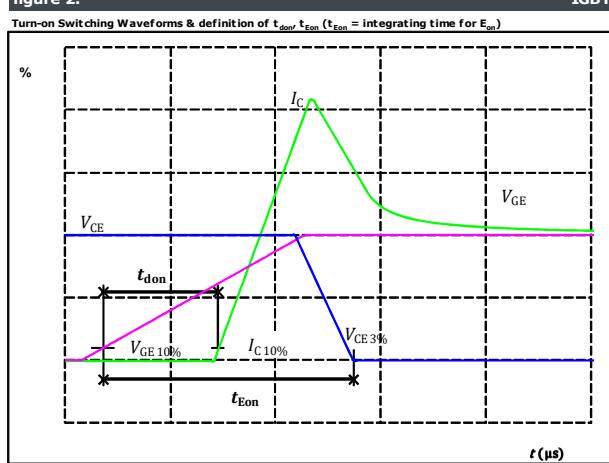
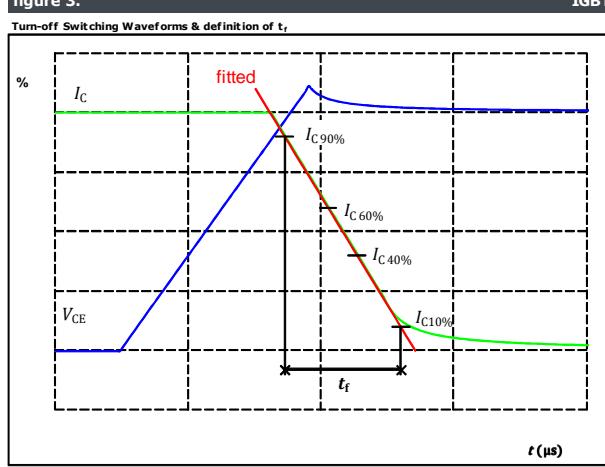
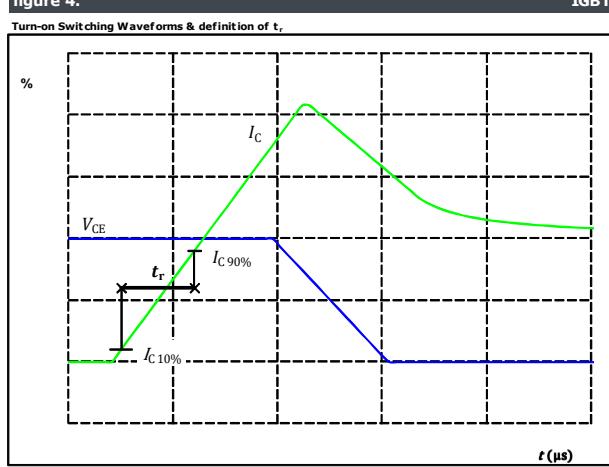


Vincotech

Boost Switching Definitions

General conditions

| | | |
|------------|---|--------|
| T_j | = | 125 °C |
| R_{gon} | = | 2 Ω |
| R_{goff} | = | 2 Ω |

figure 1.**figure 2.****figure 3.****figure 4.**

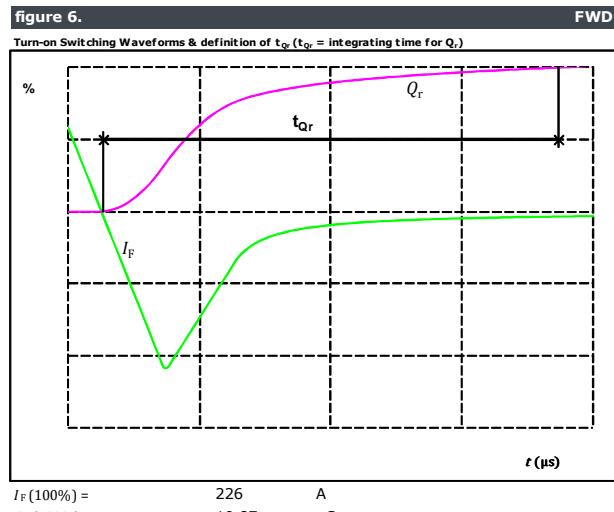
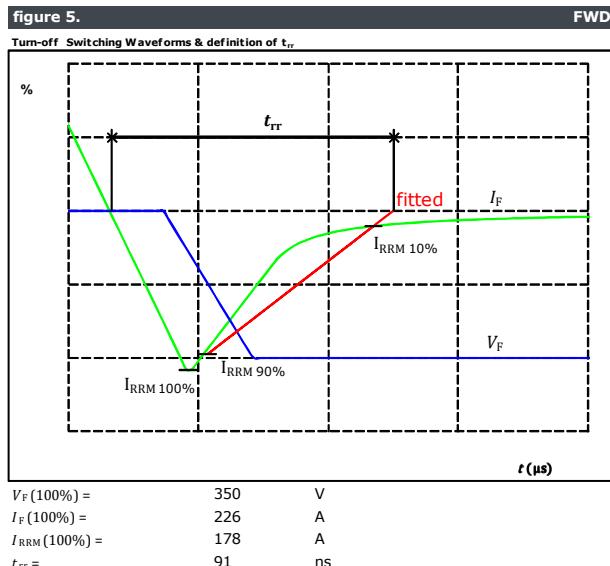


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Boost Switching Characteristics

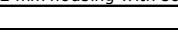




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Vincotech

| Ordering Code & Marking | | | | | | | | |
|--|---|---|---------------------------|------------------------|-----------|----------|-------|--------|
| Version | | | Ordering Code | | | | | |
| without thermal paste 12 mm housing with solder pins | | | 10-FY07NBA22SS502-M507L98 | | | | | |
| | | | | | | | | |
| | | | | | | | | |
| | | | | | | | | |
| NN-NNNNNNNNNNNNNN TTTTTVVWYY UL VIN LLLL SSSS |  |  | Text | Name | Date code | UL & VIN | Lot | Serial |
| | | | | NN-NNNNNNNNNNNN-TTTTVV | WWYY | UL VIN | LLLLL | SSSS |
| Datamatrix | Type&Ver | Lot number | Serial | Date code | | | | |
| | TTTTTVV | LLLLL | SSSS | WWYY | | | | |

Outline

| Pin table | | | |
|-----------|------|------|----------|
| Pin | X | Y | Function |
| 1 | 0 | 2,8 | N2 |
| 2 | 0 | 5,4 | N2 |
| 3 | 0 | 8 | N2 |
| 4 | 0 | 10,6 | N2 |
| 5 | 0 | 17,6 | N1 |
| 6 | 0 | 20,2 | N1 |
| 7 | 0 | 22,8 | N1 |
| 8 | 0 | 25,4 | N1 |
| 9 | 16,6 | 28,2 | DC-Boost |
| 10 | 19,2 | 28,2 | DC-Boost |
| 11 | 21,8 | 28,2 | DC-Boost |
| 12 | 24,4 | 28,2 | DC-Boost |
| 13 | 44,2 | 28,2 | Therm1 |
| 14 | 52,2 | 28,2 | Therm2 |
| 15 | 49,6 | 20,5 | Boost- |
| 16 | 52,2 | 20,5 | Boost- |
| 17 | 49,6 | 17,9 | Boost- |
| 18 | 52,2 | 17,9 | Boost- |
| 19 | 49,6 | 10,4 | Boost + |
| 20 | 52,2 | 10,4 | Boost + |
| 21 | 49,6 | 7,8 | Boost + |
| 22 | 52,2 | 7,8 | Boost + |
| 23 | 24,4 | 0 | DC+Boost |
| 24 | 21,8 | 0 | DC+Boost |
| 25 | 19,2 | 0 | DC+Boost |
| 26 | 16,6 | 0 | DC+Boost |
| 27 | 21,8 | 18,3 | S25 |
| 28 | 21,8 | 15,5 | G25 |
| 29 | 8,4 | 12,7 | G27 |
| 30 | 8,4 | 9,9 | S27 |

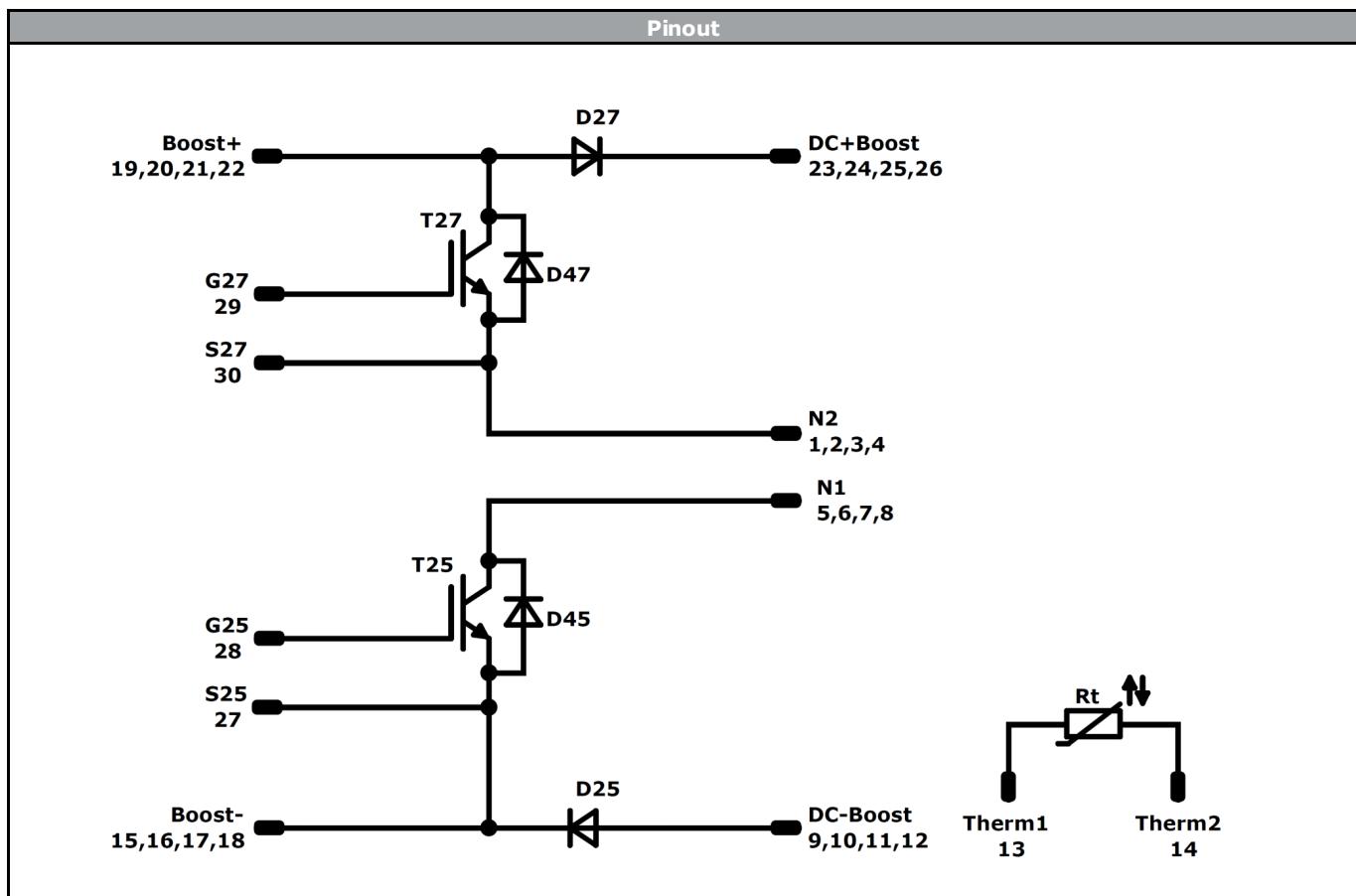
Tolerance of pinpositions $\pm 0.5\text{mm}$ at the end of pins
Dimension of coordinate axis is only offset without tolerance



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| Identification | | | | | |
|----------------|-----------|---------|---------|----------------------------|---------|
| ID | Component | Voltage | Current | Function | Comment |
| T25, T27 | IGBT | 650 V | 225 A | Boost Switch | |
| D25, D27 | FWD | 650 V | 225 A | Boost Diode | |
| D45, D47 | FWD | 650 V | 30 A | Boost Sw. Protection Diode | |
| Rt | NTC | | | Thermistor | |



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| Packaging instruction | | | |
|---------------------------------------|------|----------|-------------|
| Standard packaging quantity (SPQ) 100 | >SPQ | Standard | <SPQ Sample |

| Handling instruction | | | |
|---|--|--|--|
| Handling instructions for <i>flow 1</i> packages see vincotech.com website. | | | |

| Package data | | | |
|--|--|--|--|
| Package data for <i>flow 1</i> packages see vincotech.com website. | | | |

| UL recognition and file number | | | |
|---|--|--|---|
| This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website. | | |  |

| Document No.: | Date: | Modification: | Pages |
|---------------------------------|--------------|----------------------|--------------|
| 10-FY07NBA225S502-M507L98-D1-14 | 24 Jan. 2018 | | |

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.